NSN 5962-01-141-5694

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View Online at https://aerobasegroup.com/nsn/5962-01-141-5694 **Body Length:** Between 0.755 inches and 0.785 inches **Body Width:** Between 0.245 inches and 0.280 inches **Body Height:** 0.180 inches **Maximum Power Dissipation Rating:** 325.0 milliwatts **Operating Tempurature Range:** +0.0/+70.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** Training deb 23259 **Features Provided:** Hermetically sealed and asynchronous and programmable and w/enable and w/clock and synchronous **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 8 input **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** -0.3 volts power source and 15.0 volts power source **Time Rating Per Chacteristic:** 42.00 nanoseconds propagation delay time, low to high level output and 52.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Memory Capacity:** Unknown **Terminal Type And Quantity:** 24 printed circuit Shelf Life:

Demilitarization:

Unit Of Measure:

Yes - demil/mli

N/a

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